

Modeling Tools for Solid Oxide Fuel Cell Analysis

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Motivation

- ▶ The SOFC is a complex system:
 - Multiple physical phenomena including fluid flow, electrochemistry, electric fields, thermal field, mechanical deformations, materials compatibility
 - Physical phenomena are tightly coupled (i.e. not independent)
 - High operating temperature range
- ▶ SOFC testing is very expensive:
 - Characterization of material properties, stability, and performance required
 - Stack fabrication, assembly, monitoring, and testing are time intensive
 - Only a minimal number of experimental tests can be done to validate long term technical performance targets (e.g. 10,000 hr)
- ▶ Modeling can be used for numerical design experiments:
 - Can simulate the multiple physical phenomena
 - Can be used repetitively to quickly evaluate the effects of design changes or explore the viable design space
 - Can be used in conjunction with testing to optimize performance
 - Can investigate long term behaviors

Objectives & Approach

Objectives

- ▶ Develop integrated modeling tools to:
 - Evaluate the tightly coupled multi-physical phenomena in SOFCs
 - Aid SOFC manufacturers with materials development
 - Allow SOFC manufacturers to numerically test changes in stack design to meet DOE technical targets
- ▶ Support industry teams use of modeling for SOFC development
- ▶ Provide technical basis for SOFC stack design

Approach

- ▶ Multiphysics-based analysis tools coupled with experimental validation:
 - SOFC-MP: A multi-physics solver for computing the coupled flow-thermal-electrochemical response of multi-cell SOFC stacks
- ▶ Targeted modeling tools for specific cell design challenges:
 - Reliable sealing
 - Interface and coating durability
 - Thermal management of large stacks
 - Cathode contact paste durability
- ▶ Collaboration with ORNL and ASME to establish a stack design approach based on modeling and experiments

SOFC-MP: Capabilities and Features

▶ SOFC-MP Capabilities

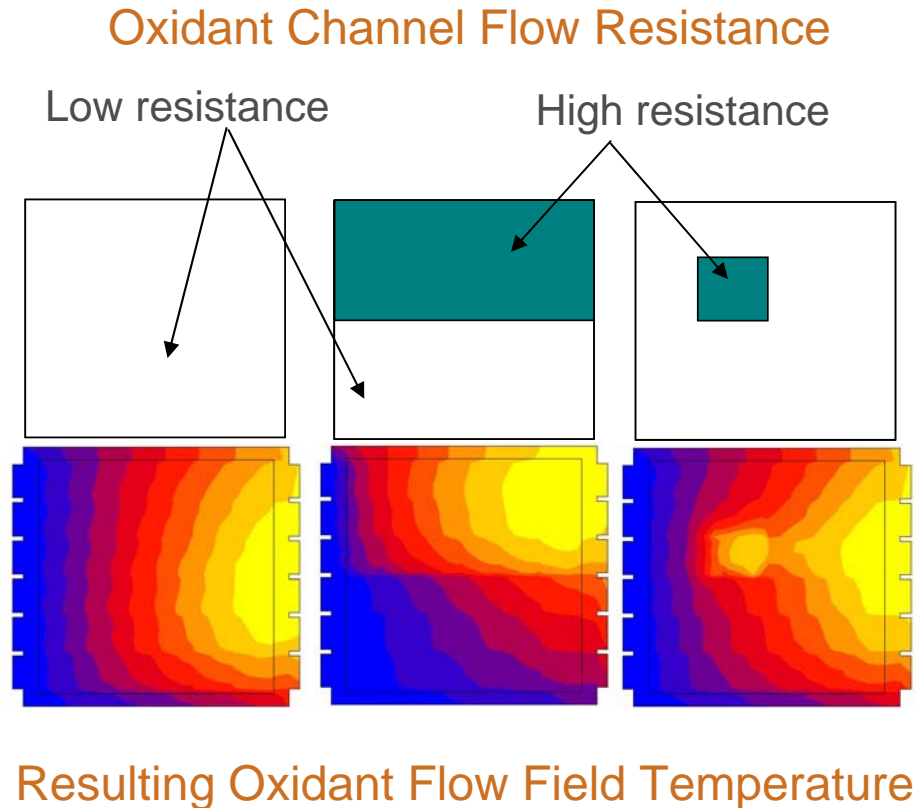
- Coupled flow, EC, and thermal solutions
- Reduced order models for computational efficiency
- Contact of incompatible meshes
- Single or multi-cell models
- Generic fuel and oxidants
- Operation at assigned voltage, current, or fuel utilization
- Thermal and electrochemical results output for visualization

▶ Recent Improvements

- Improved solution speed with use of AMG solver on PC
 - ~5hr for 8-cell stack model w/ 100k nodes and 200 solution iterations
- Elimination of memory restrictions to solver larger problem sizes
 - Models w/ 100k nodes and 55k elements on PC w/ 4Gb memory
 - Port to Linux to take advantage of large shared memory
- Improved energy balances with non-conformal meshes
- Internal code restructuring to facilitate requested enhancements

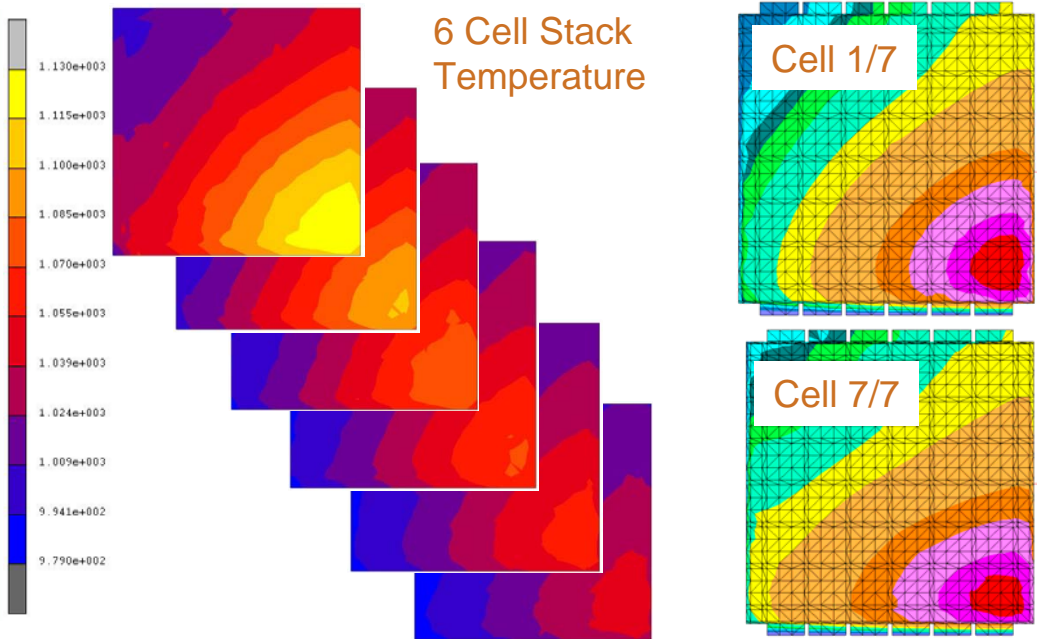
SOFC-MP: Capabilities and Features (cont'd)

- ▶ SOFC-MP has the ability to compile and utilize subroutines to customize the solution
- ▶ User subroutines can be defined to include proprietary EC models
 - Generic I-V relationship can be coded to compute voltage as a function of partial pressures, temperature, current, etc.
- ▶ User subroutines can be used to control the flow resistance
 - Different interconnect media can be simulated
 - $\frac{dP}{dL} = RV$

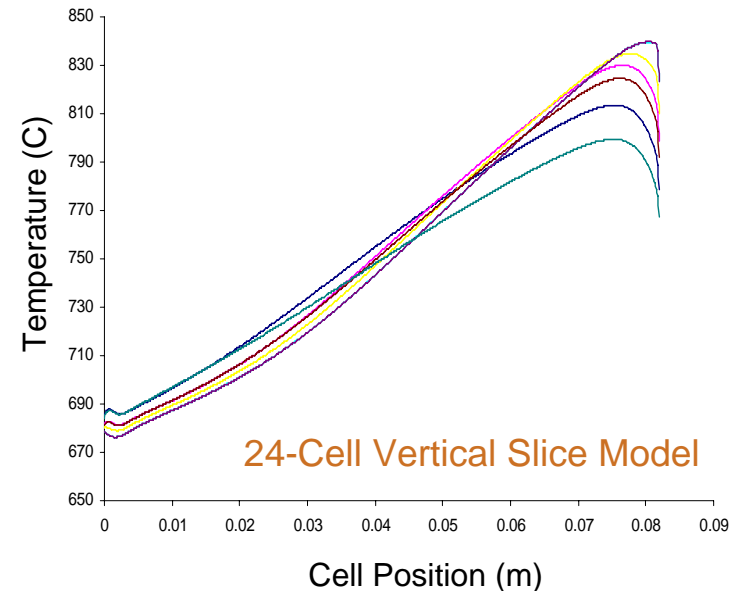


SOFC-MP: Stack Modeling Examples

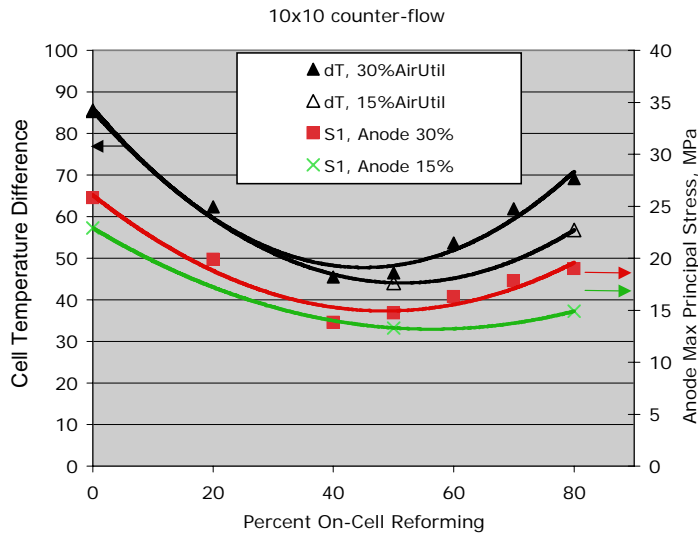
- ▶ Multi-cell 3D stacks using SOFC-MP
 - 6-cell: 360min for 76k nodes and 200 iterations
 - Stack ΔT : 160°C, Cell ΔT : 73-127°C
 - 7-cell: 18min for 88k nodes and 60 iterations
 - Faster due to low UF & different EC model
 - AMG solver: time/memory scales with # of cells



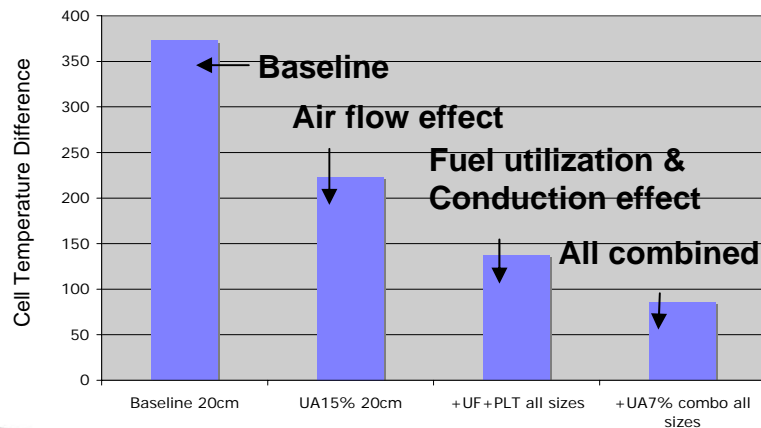
- ▶ 2D vertical stack slice model
 - Useful for co/counter-flow
 - Can be adjusted for cross-flow
 - Can handle internal reforming
 - Example: temperature profiles for various cells in 24-cell stack



Thermal Management: Internal Reforming



Temperature Difference for 20x20 cm Cross-Flow Stack



- ▶ Previous work demonstrated possible performance improvement by manipulation of the percent of reformation on-cell
 - Stack ΔT and component stress could be decreased depending upon methane content in fuel
- ▶ Separate work manipulated heat transfer and heat distribution within stack to optimize the operating condition and performance
 - Both the improved conduction, and decreased air (and fuel) utilizations decreased the stack ΔT
- ▶ Present study is a continuation of the manipulated heat transfer work to further optimize stack performance including:
 - Internal reforming
 - Pressurization

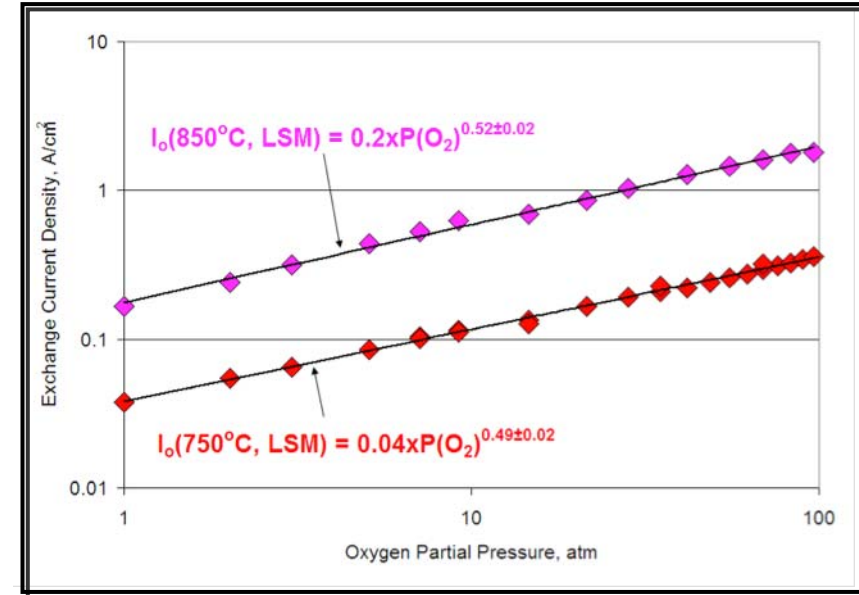
Thermal Management: Pressurization

► Optimization of stack performance will also include the effect of pressurization:

- The Nernst Potential correctly captures the pressure effect and requires no further examination
- The Butler-Volmer equation describes the activation polarization η_{act} related to the current (j) and the exchange current density (j_o). For the SOFC it can be written as:

$$\eta_{act,e} = \frac{RT}{\alpha F} \sinh^{-1} \left(\frac{j}{2j_o} \right)$$

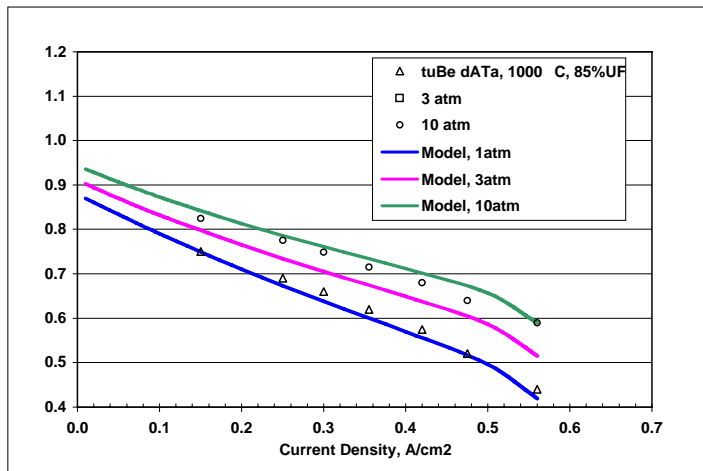
- Pederson's tests showed : $j_o = j_o(PO_2^{1/2})$
- The exchange current density model was improved by adding the pressure dependence, and applied to both electrodes as:



$$j_o = \beta \exp \left(\frac{-E_{act,e}}{RT} \right) P O_{2,e}^{\gamma}$$

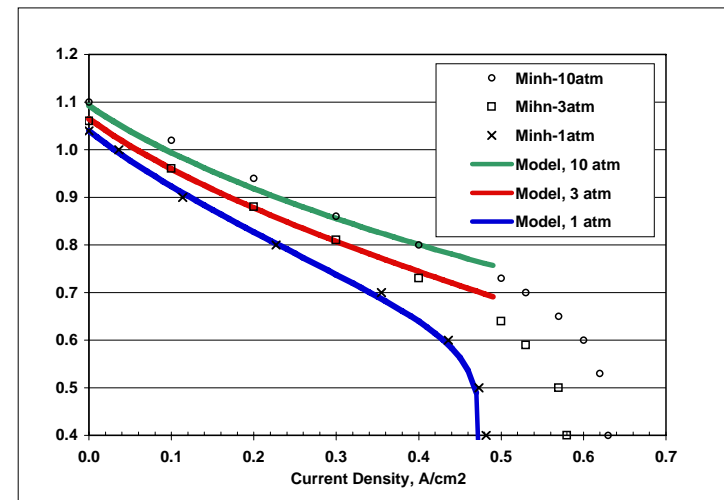
Thermal Management: Pressurization (cont'd)

- ▶ Performance improvements:
 - Increased Nernst potential
 - Decreased activation polarization
 - Increased cell voltage and electrical power -> decreased heat load
 - Decreased Heat load leads to improved thermal performance



Tubular SOFC data (Siemens), 89% H₂, 3% H₂O, running at 1, 3, and 10 atm at constant 85% UF

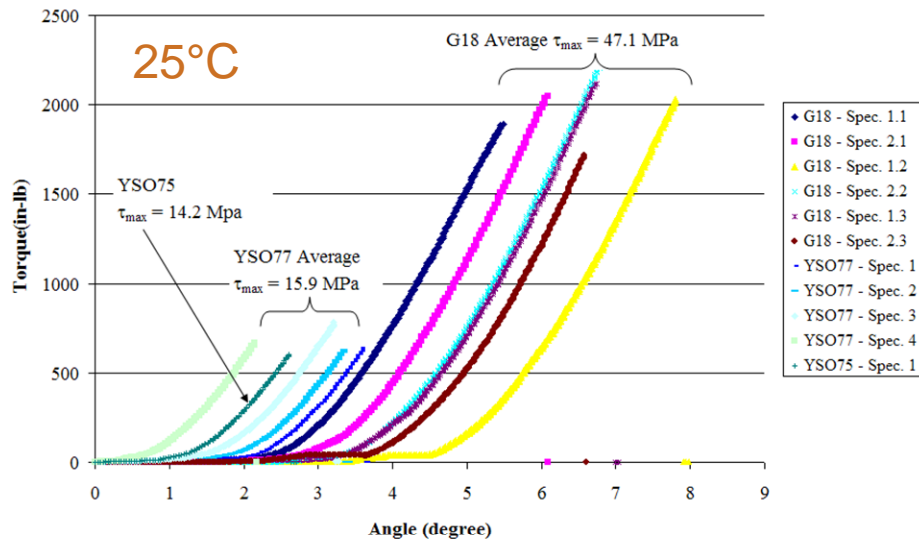
- ▶ Electrochemistry model with improved activation polarization properly characterizes the performance improvements for planar and tubular cells operating at elevated pressures



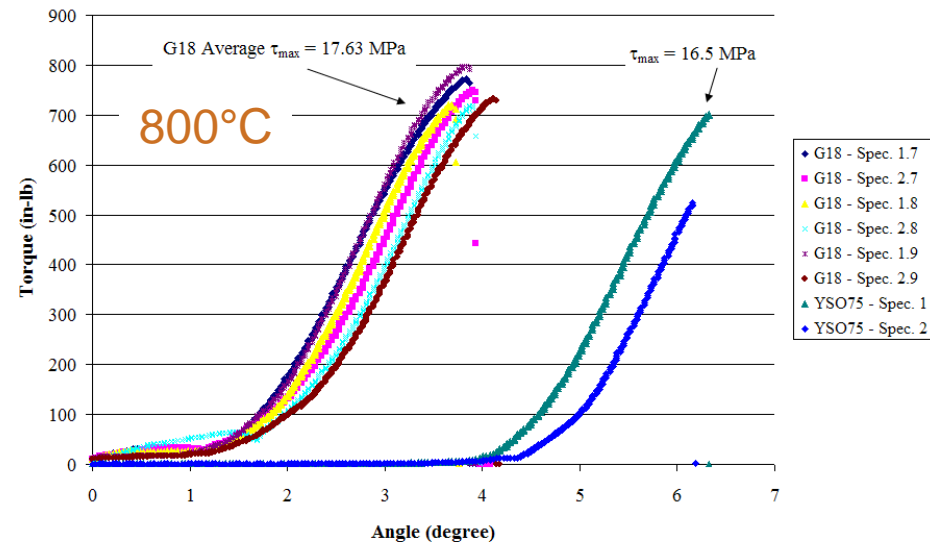
Planar SOFC data (GE), 25% H₂, 3% H₂O, 72% N₂ running at 1, 3, and 10 atm

Seal Property Characterization

- ▶ Performed shear tests of refractory glass sealants at room and elevated temperatures
 - Compared to G18 glass-ceramic



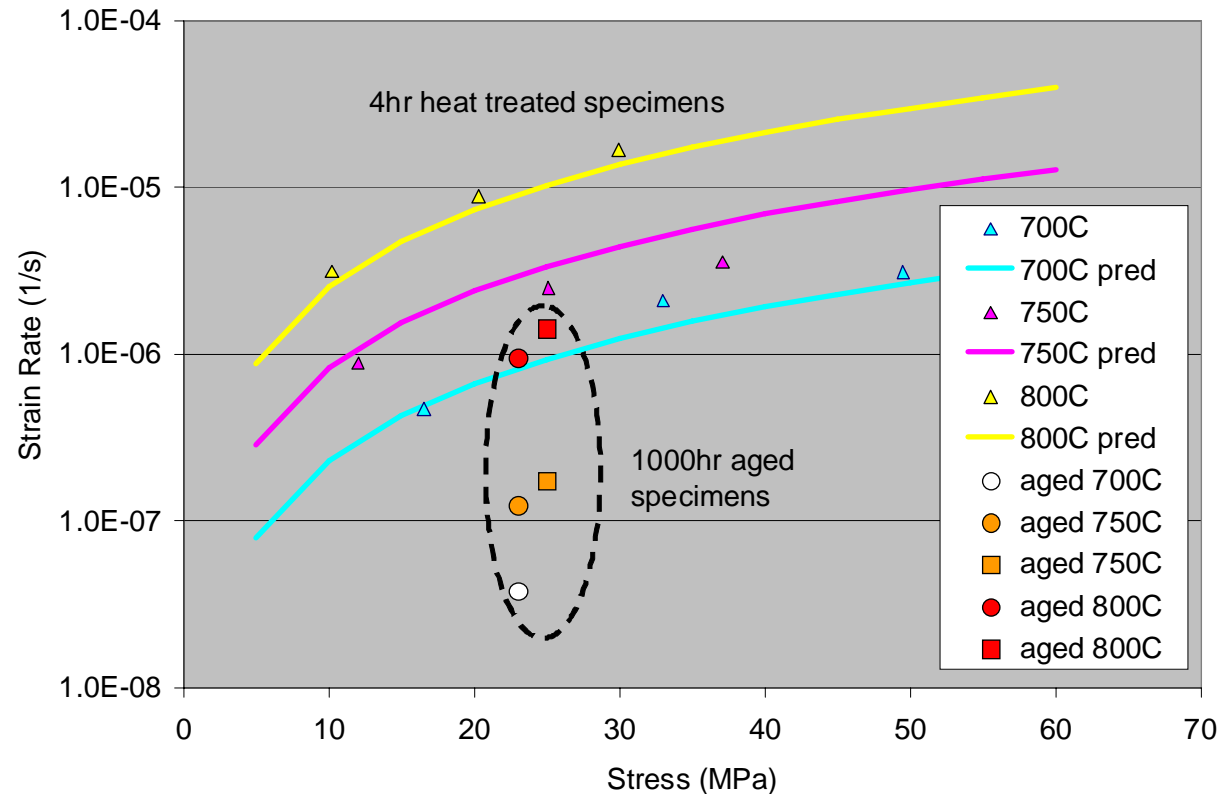
- ▶ Results
 - Room temperature strength of refractory glass about 2/3 less
 - Elevated temperature strength comparable (~7% less)



Seal Property Characterization (cont'd)

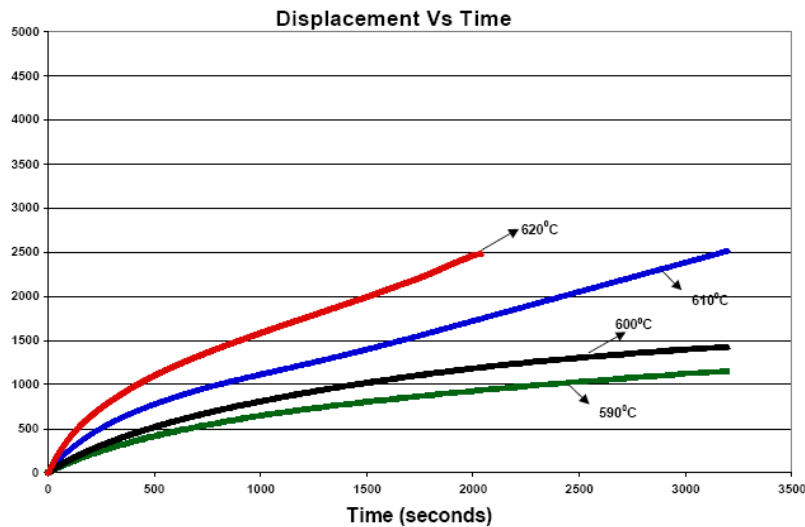
- ▶ Performed creep experiments to quantify effect of aging on time-dependent response
- ▶ Creep rate an order of magnitude less after 1000hr devitrification
- ▶ Short-term seal creep expected to accommodate high stresses initially, but much slower creep after aging

Secondary Creep Rate for Glass-Ceramic

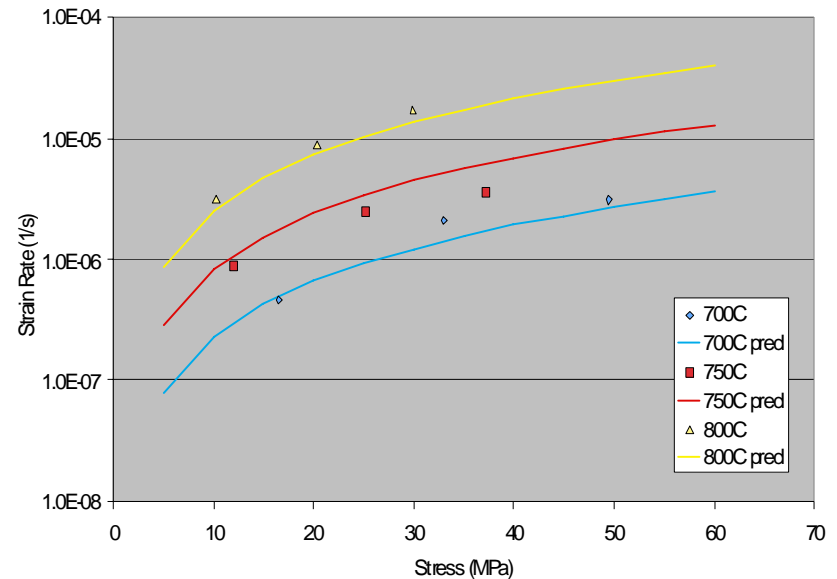


Modeling of Different Seal Glasses

UC seal-healing glass



G18 glass-ceramic



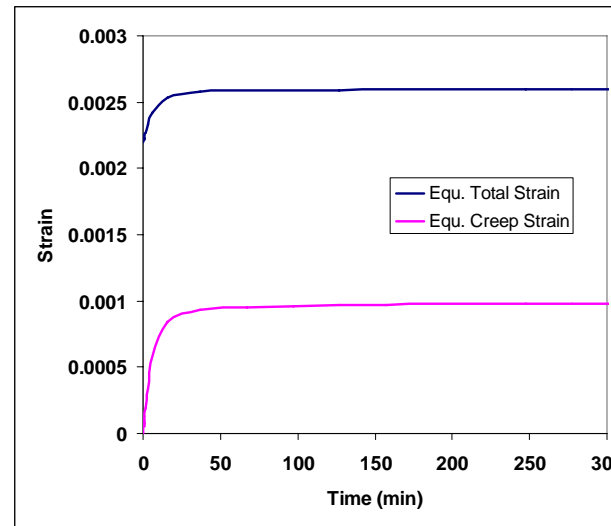
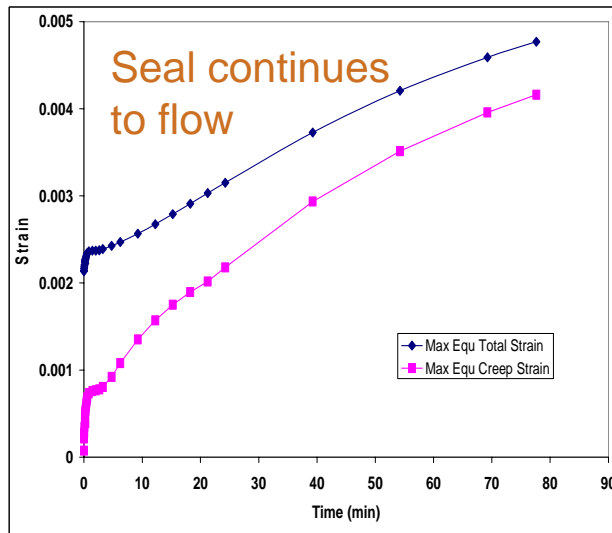
- ▶ Greatly different creep rates at 30 MPa applied stress

- UC glass: 1.0e-3/s at 1000°K
- G18 glass-ceramic: 1.0e-6/s at 973°K (700°C)

Modeling of Different Seal Glasses (cont'd)

- ▶ For G18 glass-ceramic sealant, maximum equivalent total strain and creep strain keep constant after the initial creep stage:
 - no overflow of the glass ceramic seal materials will occur during the operation of SOFC stacks
- ▶ For UC self-healing glass seal, maximum equivalent total strain and creep strain keeps increasing after one hour operation:
 - Overflow of seal glass will occur, control block of total creep deformation is necessary during the desired SOFC operating duration

UC seal-
healing
glass

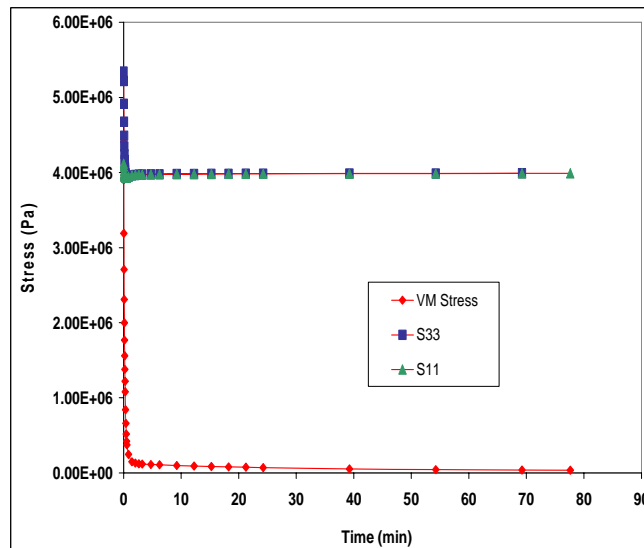


G18 glass-
ceramic

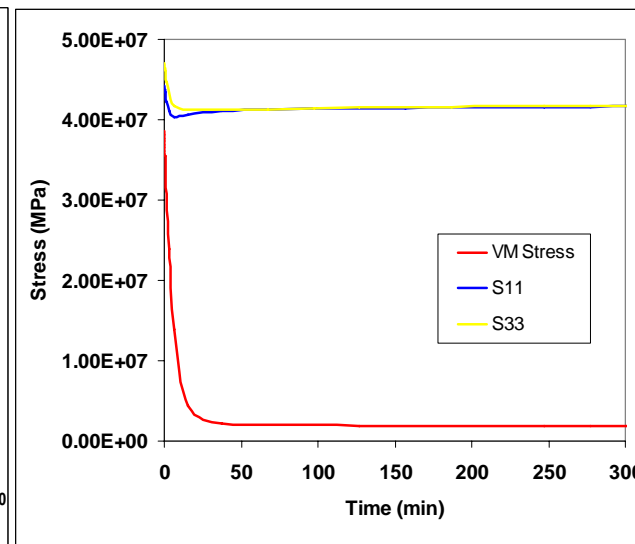
Modeling of Different Seal Glasses (cont'd)

- ▶ Maximum equivalent von Mises stress, maximum σ_{11} , and σ_{33} , for the PEN seal with the different glass sealants, respectively
- ▶ Stress results for both sealants possess similar trends
 - von Mises stress is released rapidly, and
 - normal stress σ_{11} , and σ_{33} are constant after a small drop
- ▶ Time to release the shear/deviatoric stress for G18 is much longer than UC seal healing glass

UC seal-
healing
glass

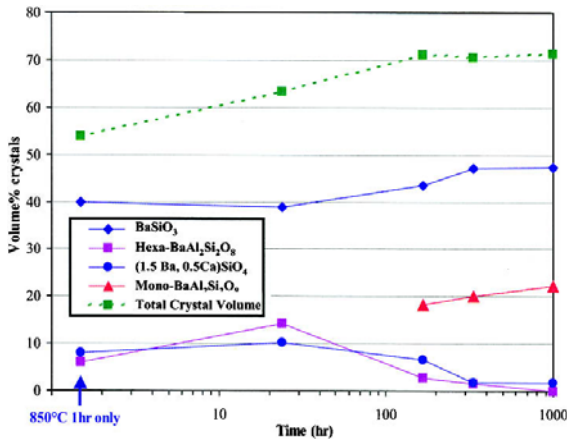


G18 glass-
ceramic



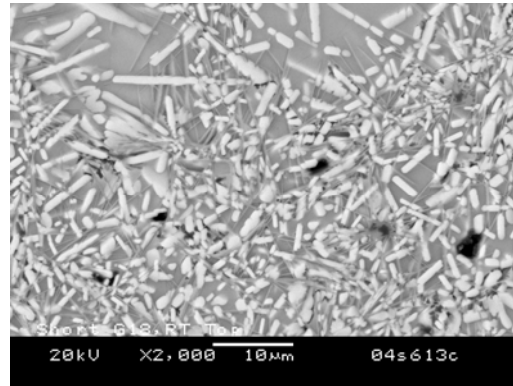
Aging/Self-Healing Behavior of G18

► Evolution of crystalline phase is time dependent

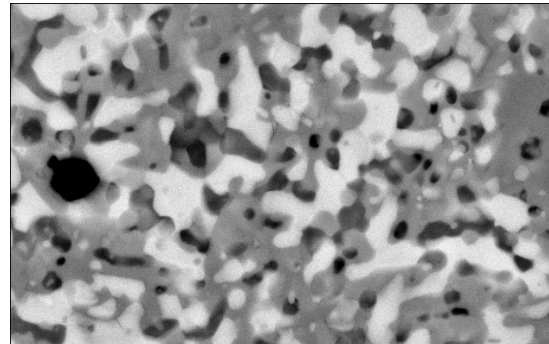


► Aging induced micro-voids in glass-ceramic

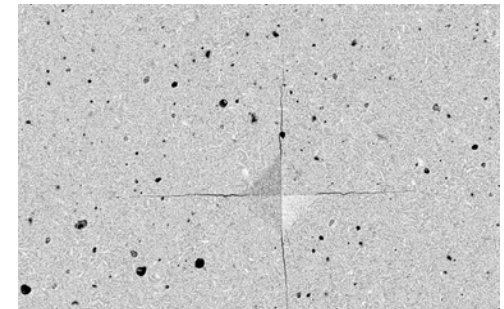
After sintering



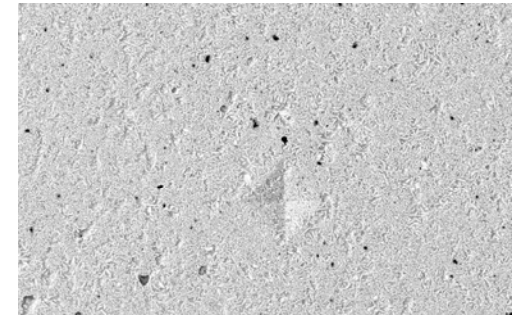
After 1000 h aging



► Glass/ceramic displays possible self-healing behavior at high temperature



Typical Vickers impression

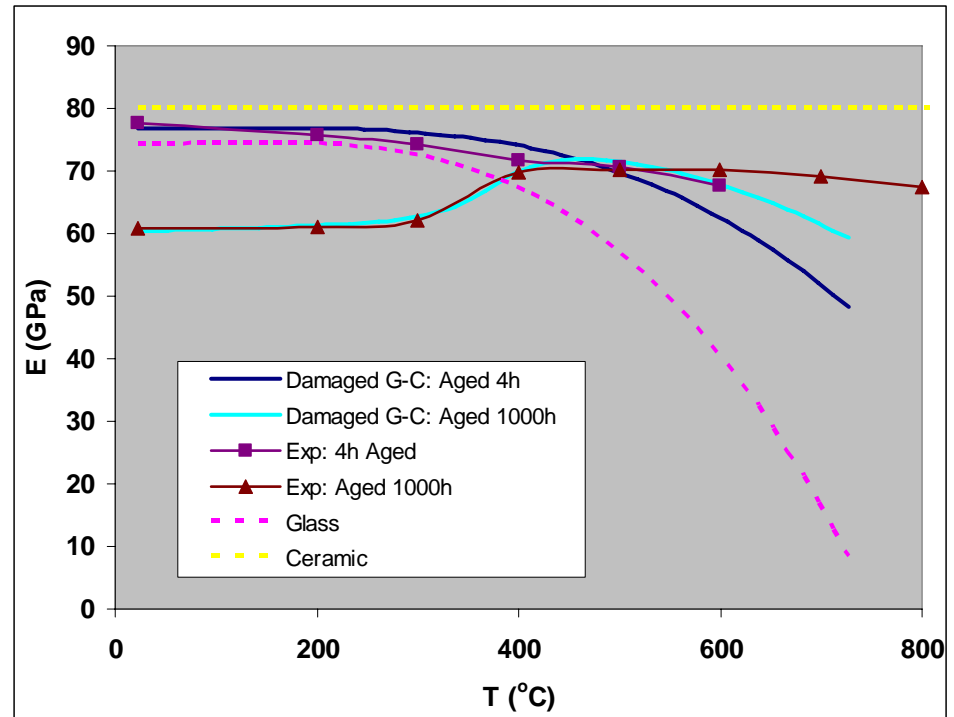


at 750°C for half an hour

Aging/Self-Healing Behavior of G18 (cont'd)

- ▶ This model includes:
 - Aging-time-dependent crystalline content model for volume evolution of crystalline phases
 - Temperature dependency
 - Degradation of modulus of glass/ceramic due to aging induced micro-damage
 - Mechanical property restore due to self-healing performance at high temperature
- ▶ This model was applicable to general glass/ceramic materials

$$E^D(t, T, D) = \left[(f_c^\infty - f_c^0 e^{-(t/A_t)}) (E_C - E_G(T)) + E_G(T) \right]^* \left\{ 1 - \frac{D_0}{\pi} (1 - e^{-t/t_c}) \left[\pi/2.0 - \arctan\left(\frac{T - T_{th}}{R}\right) \right] \right\}$$

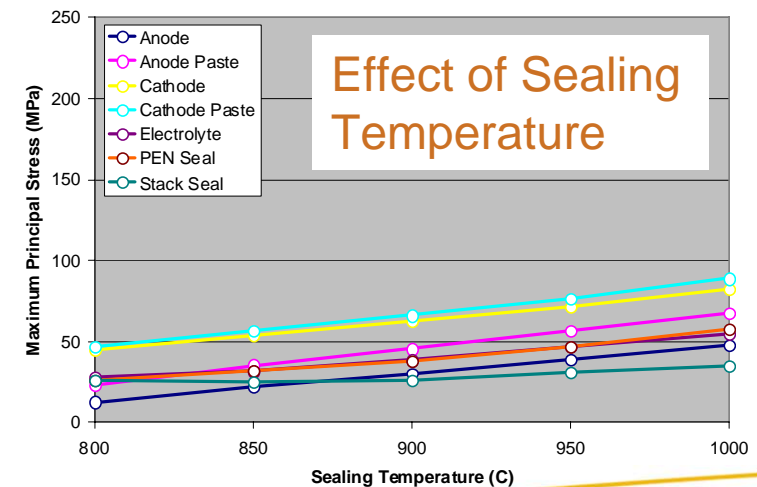
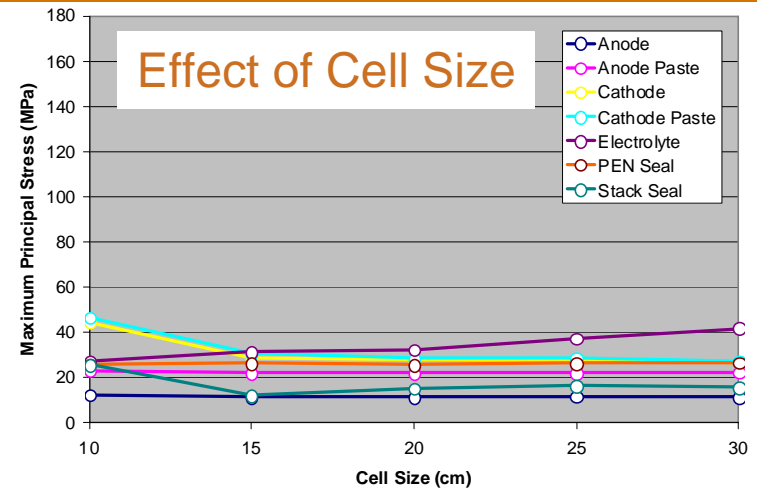


Contact Paste: Introduction

- ▶ The cathode contact layer is a highly challenging interface
 - Must make bond between ceramic cathode and metallic interconnect (likely with oxide scale and coatings)
 - Must survive oxidizing environment
 - Must likely be formed at temperatures lower than that of the conventional range for sintering of ceramics
- ▶ Modeling can aid understanding of load requirements and guide design improvements
- ▶ Areas of interest for modeling and experiments:
 - Quantification of expected interface stress levels
 - Characterization of paste mechanical/strength properties
 - Evaluation of the contact layer as a load carrying interface to reduce seal loads
 - Evaluation of contact layer stresses and reliability due to low temperature processing methods

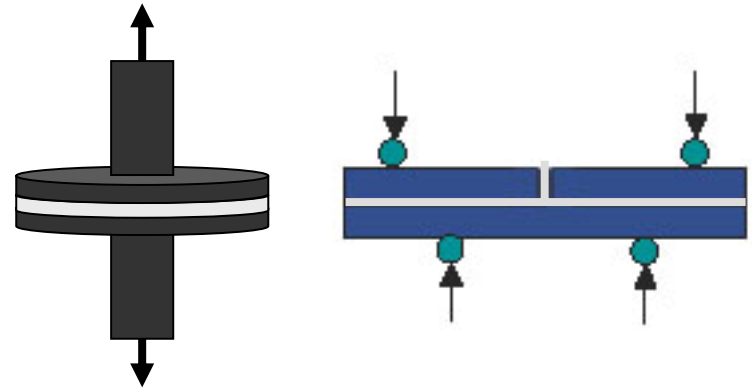
Contact Paste: Stress Levels

- ▶ Evaluated continuous paste support
 - High peeling stresses (35 MPa) and shear stresses (17 MPa) concentrated near the sealed edge of the cell at operating temperature
 - Even higher local peeling and shear stresses at shutdown
 - Cell scale-up from 10-30cm showed only moderate changes in peak stresses- dominated by edge effects
 - Sliding seals were more beneficial than rigid seals
 - Consideration of stack creep effects was beneficial for relaxing stresses
 - Higher stack sealing temperatures with rigid seals increased stresses in all the cell components

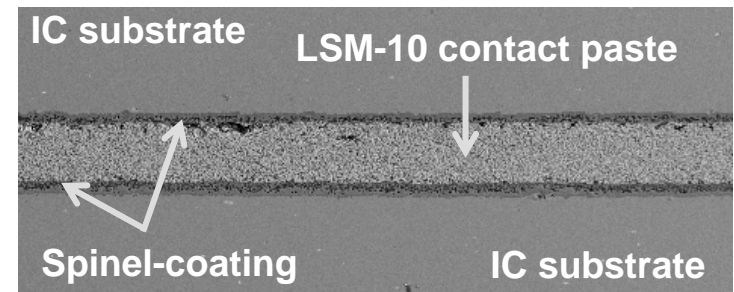


Contact Paste: Property Characterization

- ▶ Joint collaboration between PNNL and ORNL
 - Yanli Wang from ORNL visited PNNL to work on specimens fabrication
 - Continued PNNL support to ORNL for fabrication of specimens
- ▶ Experimental work in progress
 - ORNL conducting notched specimen bend tests to determine interfacial toughness of fabricated analogs
 - PNNL conducting tensile tests to determine interfacial strength of fabricated analogs
 - Beginning with spinel-coated Crofer interconnect substrate material and LSM-10 contact paste; next step to test Ce-spinel coated 441SS and LSM-10 contact paste
- ▶ Preliminary interfacial tensile strengths at test temperatures ranging from RT to 850°C indicate 1-6 MPa



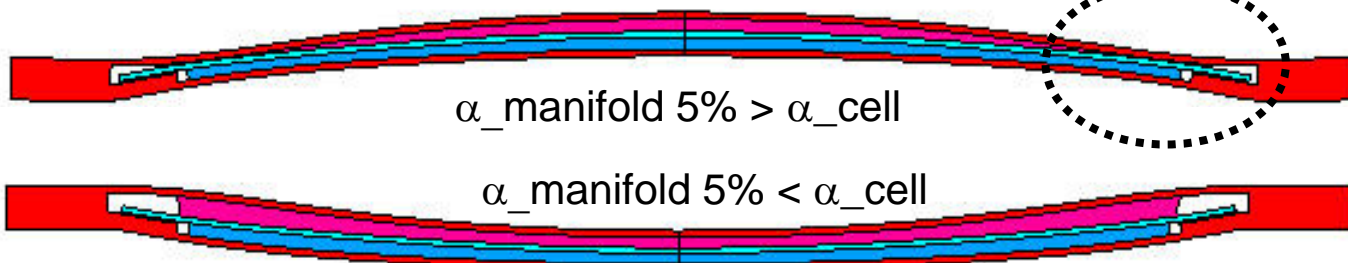
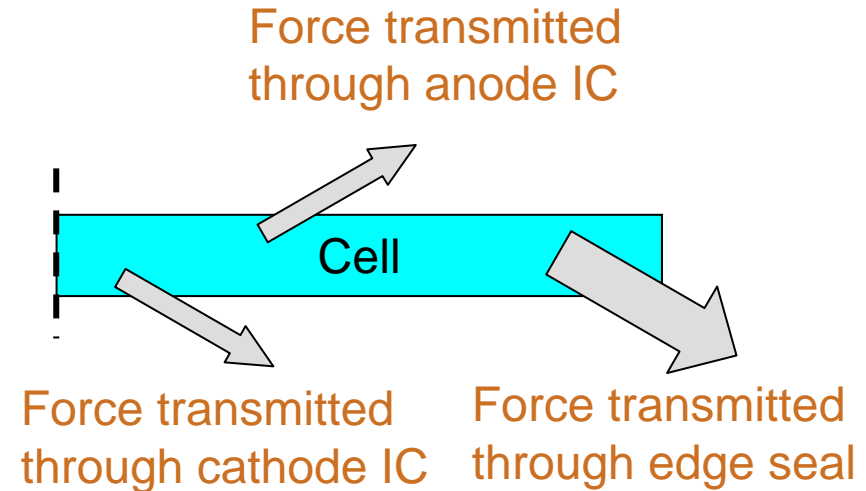
Tension test and bend bar schematic of LSM contact paste/spinel-coated IC interface



Tensile sandwich specimen cross-section of LSM contact paste/spinel-coated IC interface

Contact Paste: Load Transfer

- ▶ Q: Can a load-carrying cathode contact layer benefit the seals?
- ▶ Load transfer between cell and manifold (due to CTE mismatch) carried potentially by three parallel paths:
 - Edge seals
 - Anode interconnect
 - Cathode interconnect



- ▶ Can seal load be reduced?
- ▶ Depends on relative stiffness of components

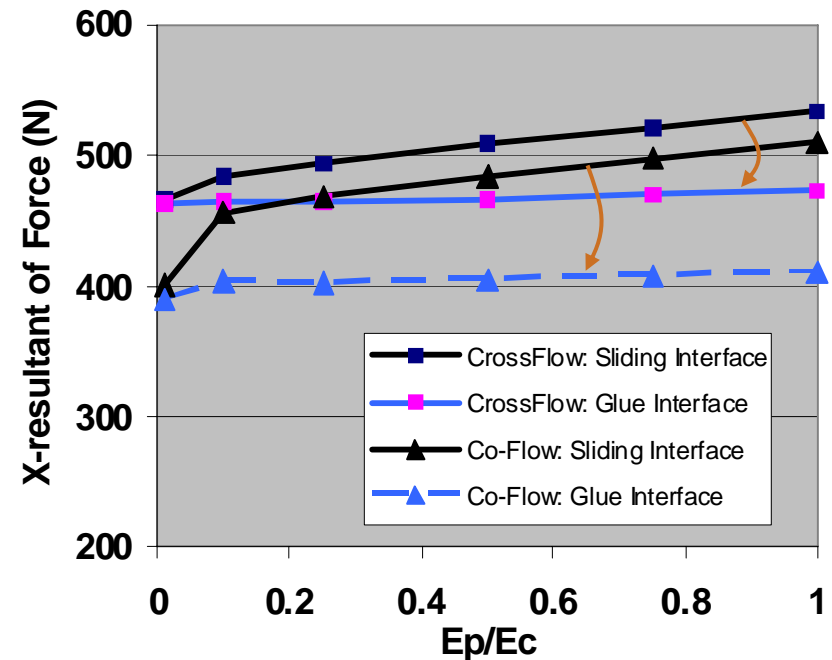
Contact Paste: Load Transfer (cont'd)

▶ Seal load dependence on contact paste design was simulated

- Co- versus cross-flow
- Bonded versus sliding contact
- Variation of paste modulus as a function of cathode modulus
- Ribbed and continuous ICs

▶ Results

- Bonded paste reduced seal shear load up to 10-20% compared to sliding interface
- Paste modulus for bonded layer had only small effect (<5%) on seal load
 - Implies low modulus sensitivity good for processing the porosity
- Seal load varied greatly (~40%) with orientation relative to rib direction
- Continuous IC evaluations still in progress



- ▶ Conclusion: load sharing concept is viable, but not fully characterized yet

Contact Paste: Sintering

Modeling Goal

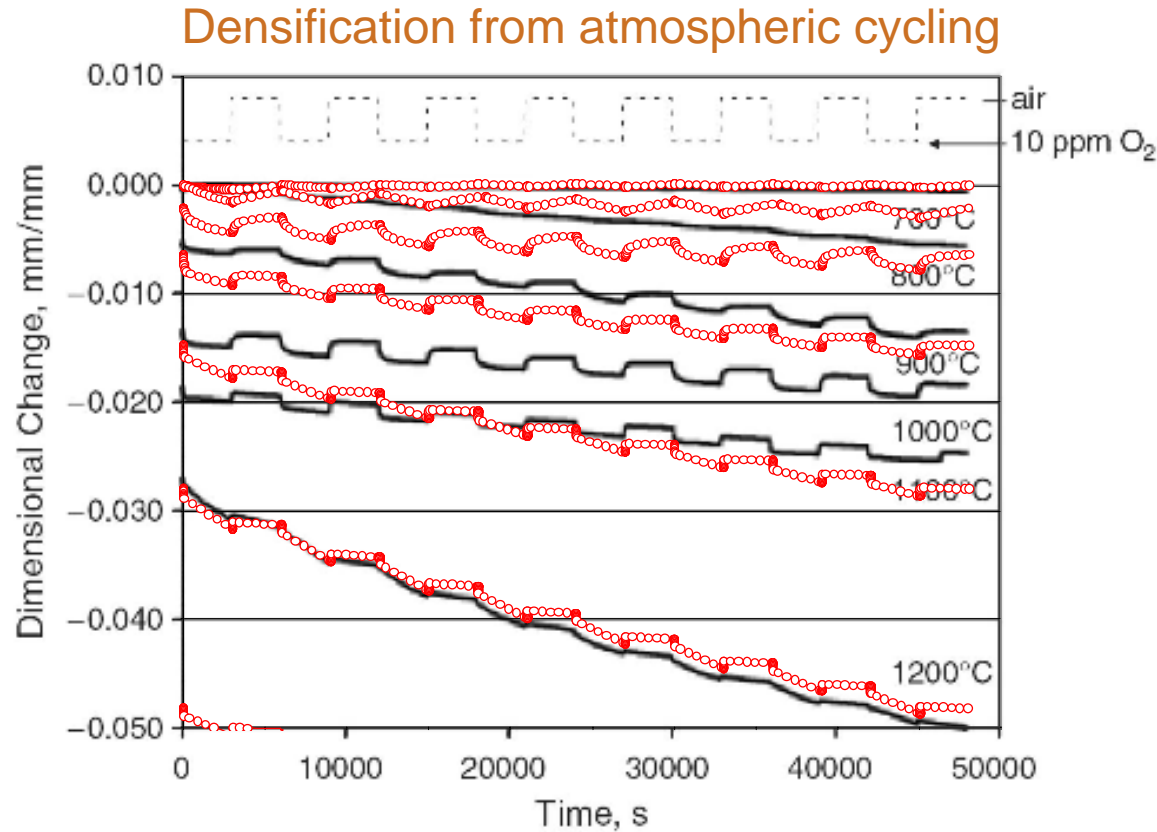
- ▶ Material and process for strong, reliable cathode contact
- ▶ Develop a model to predict the properties and stress state of the cathode contact layer including effects of:
 - Initial state/stresses due to the sintering/processing step
 - Mechanical stresses induced by any volumetric changes of the anode during reduction
 - Typical thermal stresses due to cell operation and shutdown

Technical Approach

- ▶ Implement constitutive model to predict the sintering strains and developed stresses
 - Evolution of relative density and grain size
 - Changes in elastic and strength properties as a function of relative density
- ▶ Extend the model to include the enhanced densification due to pO_2 cycling
- ▶ Test in spreadsheet model and then implement in stack models
- ▶ Evaluate structural reliability in realistic geometry

Contact Paste: Sintering (cont'd)

- ▶ Model captures densification behavior of LSM10 paste
 - Effect of pO_2 cycling and temperature changed observed in experimental tests is simulated
 - Model computes free densification strains, grain growth, and elastic property changes at different stages of sintering
 - Next implement spreadsheet model into 3D FEA tool for actual IC geometries



McCarthy BP, LR Pederson, HU Anderson, X-D Zhou, P Singh, GW Coffey, and ED Thomsen. 2007. *J Am Ceram Soc* 90(10):3255-3262.

Collaborations

- ▶ PNNL modeling staff are currently collaborating with SOFC researchers on several technical issues
- ▶ ASME design document
 - ORNL: E Lara-Curzio, Y Wang
 - ASME: J Powers, R Swayne
- ▶ Contact paste characterization
 - ORNL: E Lara-Curzio, Y Wang
 - PNNL: L Pederson, B McCarthy
- ▶ Interconnect coatings
 - PNNL: Z Yang
- ▶ SECA test cell
 - PNNL: J Stevenson, M Chou
- ▶ Modeling tool support
 - Delphi
- ▶ Seal characterization & modeling
 - U of Cincinnati: R Singh
 - GaTech: H Garmestani
 - PNNL: M Chou
- ▶ Chrome Migration
 - Carnegie Mellon: E Ryan
- ▶ Pressurized EC
 - PNNL: L Pederson

Conclusions & Ongoing Work

Conclusions

- ▶ Speed and capabilities of SOFC-MP were improved
- ▶ Cathode contact paste stresses were evaluated and a sintering model was developed
- ▶ An EC model to simulate pressurized SOFC was developed
- ▶ Seal mechanical properties continue to be characterized and modeling was used to evaluate novel sealants

Ongoing Work

- ▶ Completion of the SOFC design document
- ▶ Release of SOFC-MP v1.1
- ▶ Thermal management using coal-based fuels w/ methane and pressurization
- ▶ Characterization of contact paste mechanical strengths
- ▶ Simulation of contact paste development and cell load paths
- ▶ Improved interconnect coating systems